

Seminar on the optical properties of semiconductors

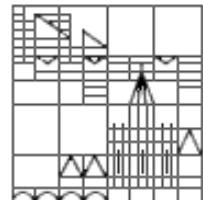
Topic

Semiconductor Bloch equations

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Semiconductor Bloch equations

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1. Introduction

So far:

- Interband transitions by Coulomb attraction between a cb electron and a vb hole
- Bound states (excitons)- time independent effects

Now:

- A number of excited electron-hole pairs and interaction between all of them (nonlinear regime)
- Time dependent effects (polarization, carrier densities)

2. Hamiltonian Equations

Starting with the Hamiltonian

$$\mathcal{H} = \mathcal{H}_{el} + \mathcal{H}_l$$

$$\begin{aligned}\mathcal{H}_{el} = & \sum_{\mathbf{k}} (E_{c,k} a_{c,\mathbf{k}}^\dagger a_{c,\mathbf{k}} + E_{v,k} a_{v,\mathbf{k}}^\dagger a_{v,\mathbf{k}}) \\ & + \frac{1}{2} \sum_{\mathbf{k}, \mathbf{k}', \mathbf{q} \neq 0} V_q (a_{c,\mathbf{k}+\mathbf{q}}^\dagger a_{c,\mathbf{k}'-\mathbf{q}}^\dagger a_{c,\mathbf{k}'} a_{c,\mathbf{k}} + a_{v,\mathbf{k}+\mathbf{q}}^\dagger a_{v,\mathbf{k}'-\mathbf{q}}^\dagger a_{v,\mathbf{k}'} a_{v,\mathbf{k}} \\ & + 2 a_{c,\mathbf{k}+\mathbf{q}}^\dagger a_{v,\mathbf{k}'-\mathbf{q}}^\dagger a_{v,\mathbf{k}'} a_{c,\mathbf{k}})\end{aligned}$$

$$\mathcal{H}_I = - \sum_{\mathbf{k}} \mathcal{E}(t) (a_{c,\mathbf{k}}^\dagger a_{v,\mathbf{k}} d_{cv} + h.c.)$$

2. Hamiltonian Equations

Transformation to electron-hole representation

$$\beta_{-\mathbf{k}}^\dagger = a_{v,\mathbf{k}} \quad \alpha_{\mathbf{k}}^\dagger = a_{c,\mathbf{k}}^\dagger$$

Electron-hole Hamiltonian

$$\begin{aligned} \mathcal{H} = & \sum_{\mathbf{k}} (E_{e,k} \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k}} + E_{h,k} \beta_{-\mathbf{k}}^\dagger \beta_{-\mathbf{k}}) \\ & + \frac{1}{2} \sum_{\mathbf{k}, \mathbf{k}', \mathbf{q} \neq 0} V_q (\alpha_{\mathbf{k}+\mathbf{q}}^\dagger \alpha_{\mathbf{k}'-\mathbf{q}}^\dagger \alpha_{\mathbf{k}'} \alpha_{\mathbf{k}} + \beta_{\mathbf{k}+\mathbf{q}}^\dagger \beta_{\mathbf{k}'-\mathbf{q}}^\dagger \beta_{\mathbf{k}'} \beta_{-\mathbf{k}} - 2 \alpha_{\mathbf{k}+\mathbf{q}}^\dagger \beta_{\mathbf{k}'-\mathbf{q}}^\dagger \beta_{\mathbf{k}'} \alpha_{\mathbf{k}}) \\ & - \sum_{\mathbf{k}} \mathcal{E}(t) (d_{cv} \alpha_{\mathbf{k}}^\dagger \beta_{-\mathbf{k}}^\dagger + \text{h.c.}) + \cancel{\text{constant terms}} \end{aligned}$$

single particle energies: $E_{e,k} = E_{c,k} = \hbar \epsilon_{e,k}$

$$E_{h,k} = -E_{v,k} + \sum_{\mathbf{q} \neq 0} V_q = \hbar \epsilon_{h,k}$$

2. Hamiltonian Equations

Elements of the reduced density matrix

$$\langle \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k}} \rangle = n_{e,\mathbf{k}}(t)$$

$$\langle \beta_{-\mathbf{k}}^\dagger \beta_{-\mathbf{k}} \rangle = n_{h,\mathbf{k}}(t)$$

$$\langle \beta_{-\mathbf{k}} \alpha_{\mathbf{k}} \rangle = P_{he}(\mathbf{k}, t) \equiv P_{\mathbf{k}}(t)$$

Equations of motion $i \hbar \frac{\partial}{\partial t} \langle A \rangle = \langle [H, A] \rangle$

for polarization

$$\hbar \left[i \frac{d}{dt} - (\epsilon_{e,k} + \epsilon_{h,k}) \right] P_{\mathbf{k}} = (n_{e,\mathbf{k}} + n_{h,\mathbf{k}} - 1) d_{vc} \mathcal{E}(t)$$

$$+ \sum_{\mathbf{k}', \mathbf{q} \neq 0} V_q \left(\langle \alpha_{\mathbf{k}' + \mathbf{q}}^\dagger \beta_{-\mathbf{k} + \mathbf{q}} \alpha_{\mathbf{k}'} \alpha_{\mathbf{k}} \rangle - \langle \beta_{\mathbf{k}' + \mathbf{q}}^\dagger \beta_{-\mathbf{k} + \mathbf{q}} \beta_{\mathbf{k}'} \alpha_{\mathbf{k}} \rangle \right.$$

$$\left. + \langle \beta_{-\mathbf{k}} \alpha_{\mathbf{k}' - \mathbf{q}}^\dagger \alpha_{\mathbf{k}'} \alpha_{\mathbf{k} - \mathbf{q}} \rangle - \langle \beta_{-\mathbf{k}} \beta_{\mathbf{k}' - \mathbf{q}}^\dagger \beta_{\mathbf{k}'} \alpha_{\mathbf{k} - \mathbf{q}} \rangle \right)$$

2. Hamiltonian Equations

Equations of motion for the electron population

$$\begin{aligned} \hbar \frac{\partial}{\partial t} n_{e,\mathbf{k}} = & -2 \operatorname{Im} \left[d_{cv} \mathcal{E}(t) P_{\mathbf{k}}^* \right] \\ & + i \sum_{\mathbf{k}', \mathbf{q} \neq 0} V_q \left(\langle \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k}' - \mathbf{q}}^\dagger \alpha_{\mathbf{k} - \mathbf{q}} \alpha_{\mathbf{k}'} \rangle - \langle \alpha_{\mathbf{k} + \mathbf{q}}^\dagger \alpha_{\mathbf{k}' - \mathbf{q}}^\dagger \alpha_{\mathbf{k}} \alpha_{\mathbf{k}'} \rangle \right. \\ & \left. + \langle \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k} - \mathbf{q}} \beta_{\mathbf{k}' - \mathbf{q}}^\dagger \beta_{\mathbf{k}'} \rangle - \langle \alpha_{\mathbf{k} + \mathbf{q}}^\dagger \alpha_{\mathbf{k}} \beta_{\mathbf{k}' - \mathbf{q}}^\dagger \beta_{\mathbf{k}'} \rangle \right) , \end{aligned}$$

Equations of motion for the hole population

$$\begin{aligned} \hbar \frac{\partial}{\partial t} n_{h,\mathbf{k}} = & -2 \operatorname{Im} \left[d_{cv} \mathcal{E}(t) P_{\mathbf{k}}^* \right] \\ & + i \sum_{\mathbf{k}', \mathbf{q} \neq 0} V_q \left(\langle \beta_{-\mathbf{k}}^\dagger \beta_{\mathbf{k}' - \mathbf{q}}^\dagger \beta_{-\mathbf{k} - \mathbf{q}} \beta_{\mathbf{k}'} \rangle - \langle \beta_{-\mathbf{k} + \mathbf{q}}^\dagger \beta_{\mathbf{k}' - \mathbf{q}}^\dagger \beta_{-\mathbf{k}} \beta_{\mathbf{k}'} \rangle \right. \\ & \left. + \langle \alpha_{\mathbf{k}' + \mathbf{q}}^\dagger \alpha_{\mathbf{k}'} \beta_{-\mathbf{k}}^\dagger \beta_{-\mathbf{k} + \mathbf{q}} \rangle - \langle \alpha_{\mathbf{k}' + \mathbf{q}}^\dagger \alpha_{\mathbf{k}'} \beta_{-\mathbf{k} - \mathbf{q}}^\dagger \beta_{-\mathbf{k}} \rangle \right) . \end{aligned}$$

2. Hamiltonian Equations

For simplification: split the four-operator terms
into two-operator terms of

Densities, interband polarization plus
unfactorized rest

$$\langle 4 \text{ terms} \rangle = \langle 2 \text{ terms} \rangle \langle 2 \text{ terms} \rangle + \text{unfactorized}$$

by separating into Hartree-Fock and scatt. Parts

$$\frac{\partial}{\partial t} \langle A \rangle = \frac{\partial}{\partial t} \langle A \rangle_{HF} + \frac{\partial}{\partial t} \langle A \rangle|_{scatt}$$

2. Hamiltonian Equations

Hartree-Fock Approximation for one term

$$\langle \alpha_i^\dagger \alpha_j^\dagger \alpha_k \alpha_l \rangle \simeq \langle \alpha_i^\dagger \alpha_l \rangle \langle \alpha_j^\dagger \alpha_k \rangle - \langle \alpha_i^\dagger \alpha_k \rangle \langle \alpha_j^\dagger \alpha_l \rangle$$

$$\begin{aligned} \langle \alpha_{k'+q}^\dagger \beta_{-k+q} \alpha_{k'} \alpha_k \rangle_{HF} &\simeq \langle \alpha_{k'+q}^\dagger \alpha_{k'} \rangle \langle \beta_{-k+q} \alpha_{k'} \rangle - \langle \alpha_{k'+q}^\dagger \alpha_{k'} \rangle \langle \beta_{-k+q} \alpha_k \rangle \\ &= \delta_{k, k'+q} \langle \alpha_k^\dagger \alpha_k \rangle \langle \beta_{-k+q} \alpha_{k-q} \rangle - \delta_{q_0} \langle \alpha_{k'}^\dagger \alpha_{k'} \rangle \langle \beta_{-k} \alpha_k \rangle \end{aligned}$$

$$\text{with } \sum_{k', q \neq 0} V_q \delta_{q_0} \langle \alpha_{k'}^\dagger \alpha_{k'} \rangle \langle \beta_{-k} \alpha_k \rangle = 0$$

$$\langle \alpha_{k'+q}^\dagger \beta_{-k+q} \alpha_{k'} \alpha_k \rangle_{HF} \simeq \delta_{k, k'+q} \langle \alpha_k^\dagger \alpha_k \rangle \langle \beta_{-k+q} \alpha_{k-q} \rangle = \delta_{k, k'+q} n_{e,k}(t) P_{k+q}(t)$$

[similar for all 4 operator terms]

2. Hamiltonian Equations

Equations of motion (with factorization)

$$\frac{\partial P_{\mathbf{k}}}{\partial t} = -i(e_{e,k} + e_{h,k})P_{\mathbf{k}}$$

$$- \frac{i}{\hbar}(n_{e,\mathbf{k}} + n_{h,\mathbf{k}} - 1) \left[d_{cv}\mathcal{E}(t) + \sum_{\mathbf{q} \neq \mathbf{k}} V_{|\mathbf{k}-\mathbf{q}|} P_{\mathbf{q}} \right] + \frac{\partial P_{\mathbf{k}}}{\partial t} \Big|_{scatt}$$

$$\frac{\partial n_{e,\mathbf{k}}}{\partial t} = -\frac{2}{\hbar} \text{Im} \left\{ \left[d_{cv}\mathcal{E}(t) + \sum_{\mathbf{q} \neq \mathbf{k}} V_{|\mathbf{k}-\mathbf{q}|} P_{\mathbf{q}} \right] P_{\mathbf{k}}^* \right\} + \frac{\partial n_{e,\mathbf{k}}}{\partial t} \Big|_{scatt}$$

$$\frac{\partial n_{h,\mathbf{k}}}{\partial t} = -\frac{2}{\hbar} \text{Im} \left\{ \left[d_{cv}\mathcal{E}(t) + \sum_{\mathbf{q} \neq \mathbf{k}} V_{|\mathbf{k}-\mathbf{q}|} P_{\mathbf{q}} \right] P_{\mathbf{k}}^* \right\} + \frac{\partial n_{h,\mathbf{k}}}{\partial t} \Big|_{scatt}$$

single particle energies $\hbar e_{i,k} = \hbar \epsilon_{i,k} - \sum_q V_{|k-q|} n_{i,q}$ $i = e, h$

2. Hamiltonian Equations

Generalized Rabi frequency

$$\omega_{R,k} = \frac{1}{\hbar} \left(d_{cv} \mathcal{E} + \sum_{q \neq k} V_{|k-q|} P_q \right)$$

Semiconductor Bloch equations

$$\frac{\partial P_k}{\partial t} = -i(e_{e,k} + e_{h,k})P_k - i(n_{e,k} + n_{h,k} - 1)\omega_{R,k} + \frac{\partial P_k}{\partial t} \Big|_{scatt}$$

$$\frac{\partial n_{e,k}}{\partial t} = -2 \operatorname{Im}(\omega_{R,k} P_k^*) + \frac{\partial n_{e,k}}{\partial t} \Big|_{scatt}$$

$$\frac{\partial n_{h,k}}{\partial t} = -2 \operatorname{Im}(\omega_{R,k} P_k^*) + \frac{\partial n_{h,k}}{\partial t} \Big|_{scatt}$$

2. Hamiltonian Equations

Generalized Rabi frequency

$$\omega_{R,k} = \frac{1}{\hbar} \left(d_{cv} \mathcal{E} + \sum_{q \neq k} V_{|k-q|} P_q \right)$$

Semiconductor Bloch equations

$$\frac{\partial P_k}{\partial t} = -i(e_{e,k} + e_{h,k})P_k - i(n_{e,k} + n_{h,k} - 1)\omega_{R,k}$$

$$+ \frac{\partial P_k}{\partial t} \Big|_{scatt}$$

dephasing

$$\frac{\partial n_{e,k}}{\partial t} = -2 \operatorname{Im}(\omega_{R,k} P_k^*) + \frac{\partial n_{e,k}}{\partial t} \Big|_{scatt}$$

$$\frac{\partial n_{h,k}}{\partial t} = -2 \operatorname{Im}(\omega_{R,k} P_k^*) + \frac{\partial n_{h,k}}{\partial t} \Big|_{scatt}$$

relaxation

2. Hamiltonian Equations

Several relevant regimes:

- The low excitation regime (excitons dominate)
- The high excitation regime ($e^- - e^-$ dominates)
- The quasi-equilibrium regime ($n_e \approx f_e$, $n_h \approx f_h$)
- The ultrafast regime

3. Low Excitation Regime

Bloch Equations without non-linear terms describe excitation in semiconductors with low electron hole pair densities

- nonlinear terms include terms for densities and/or Polarization (exchange terms) like $\sim n \cdot P$

Semiconductor Bloch Eq. with linear terms only:

$$\hbar \left[i \frac{\partial}{\partial t} - (\epsilon_{e,k} + \epsilon_{h,k}) \right] P_k = (n_{e,k} + n_{h,k} - 1) d_{cv} E(t) - \sum_{q \neq k} V_{|k-q|} P_q$$

$$\hbar \frac{\partial}{\partial t} n_{e,k} = i \left[d_{cv} E(t) P_k^\dagger - c.c. \right] \quad \text{and} \quad n_{h,k} = n_{e,k}$$

3. Low Excitation Regime

Transformation to realspace

initial conditions: $n_{h,k} = n_{e,k} = P_{cv,k} = 0$

with $H_{eh} = E_g - \frac{\hbar^2 \nabla^2}{2m_r} - V(r)$

$$i\hbar \frac{\partial}{\partial t} P(r) = H_{eh} P(r) + d_{cv} E(t) [2n(r) - \delta(r)]$$

$$\hbar \frac{\partial}{\partial t} n(r) = i [d_{cv} E(t) P_k^* - c.c.]$$

Equations yield local charge neutrality $n_e(r) = n_h(-r) \equiv n(r)$

3. Low Excitation Regime

multiply equations by $\psi_\lambda(r)$ and integrate of r:

$$i\hbar \frac{\partial}{\partial t} P_\lambda = \hbar \epsilon_\lambda P_\lambda + d_{cv} E(t) [2n_\lambda - \psi_\lambda(r=0)]$$

$$\hbar \frac{\partial}{\partial t} n_\lambda = i d_{cv} E(t) P_\lambda^* + i d_{cv}^* E(t) P_\lambda$$

introducing the following definitions:

$$\int d^3r \psi_\lambda(r) P(r) = P_\lambda$$

$$\int d^3r \psi_\lambda(r) n(r) = n_\lambda$$

$$P_\lambda = \psi_\lambda(r=0) \tilde{P}_\lambda, \quad n_\lambda = \psi_\lambda(r=0) \tilde{n}_\lambda$$

3. Low Excitation Regime

We obtain the simplified equation of motion:

$$\begin{aligned} i\hbar\frac{\partial}{\partial t}\tilde{P}_\lambda &= \hbar\epsilon_\lambda\tilde{P}_\lambda + d_{cv}E(t)[2\tilde{n}_\lambda - 1] \\ \hbar\frac{\partial}{\partial t}\tilde{n}_\lambda &= id_{cv}E(t)\tilde{P}_\lambda^* + id_{cv}^*E(t)\tilde{P}_\lambda \end{aligned}$$

equivalent to Optical Bloch Equations (but dynamics described by excitons)

3. Low Excitation Regime

Polarization is described by

$$P(t) = \sum_k P_k(t) d_{vc} + c.c. = d_{cv} P(r=0) + c.c.$$

with $P(r) = \sum_{\lambda} P_{\lambda} \psi_{\lambda}^*(r)$ we get:

$$P(t) = d_{cv} P(r=0) + c.c. = d_{cv} \sum_{\lambda} P_{\lambda} \psi_{\lambda}^*(r=0) + c.c.$$

Inserting $P_{\lambda} = \psi_{\lambda}(r=0) \tilde{P}_{\lambda}$ for $r=0$ we get the optical Polarization as

$$P(t) = d_{cv} \sum_{\lambda} [\psi_{\lambda}(r=0)]^2 \tilde{P}_{\lambda} + c.c.$$

(describes inhomogeneously broadened two-level system)

4. Scattering Terms

All interaction effects beyond the mean field approximation are contained in the scatt terms.

The scattering terms describe:

- Dephasing for interband polarization
 - = decay of quantum coherence in coherently excited system
- Relaxation of electron and hole distributions

4. Scattering Terms

Dissipation kinetics of intraband relaxation in low excitation regime dominated by:

- Impurity scattering
- Scattering of excited carriers with phonons

fastest dynamics by longitudinal optical phonon scattering

high excitation regime:

- Dissipation process dominated by carrier carrier collision (dense electron-hole plasma)

4.1 Phenomenological description

a simple relaxation model needs at least two relaxation times T'_1 and T_1 for densities:

$$\frac{dn_{e,k}}{dt} \Big|_{scatt} = \frac{f_{e,k} - n_{e,k}(t)}{T'_1} - \frac{n_{e,k}(t)}{T_1}$$

T_1 : recombination time of carriers

T'_1 : intraband relaxation

and a dephasing time T_2 for polarization:

$$\frac{dP_k}{dt} \Big|_{scatt} = -\frac{P_k}{T_2}$$

4.2 Beyond HF approximation

Show general treatment for adding scatt. and dephasing rates to the Semicond. Bloch Eq. and look at the final results

- Equation of motion for electron population

$$\begin{aligned} \hbar \frac{\partial}{\partial t} n_{e,\mathbf{k}} = & -2 \operatorname{Im} \left[d_{cv} \mathcal{E}(t) P_{\mathbf{k}}^* \right] \\ & + i \sum_{\mathbf{k}', \mathbf{q} \neq 0} V_q \left(\langle \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k}'-\mathbf{q}}^\dagger \alpha_{\mathbf{k}-\mathbf{q}} \alpha_{\mathbf{k}'} \rangle - \langle \alpha_{\mathbf{k}+\mathbf{q}}^\dagger \alpha_{\mathbf{k}'-\mathbf{q}}^\dagger \alpha_{\mathbf{k}} \alpha_{\mathbf{k}'} \rangle \right. \\ & \left. + \langle \alpha_{\mathbf{k}}^\dagger \alpha_{\mathbf{k}-\mathbf{q}} \beta_{\mathbf{k}'-\mathbf{q}}^\dagger \beta_{\mathbf{k}'} \rangle - \langle \alpha_{\mathbf{k}+\mathbf{q}}^\dagger \alpha_{\mathbf{k}} \beta_{\mathbf{k}'-\mathbf{q}}^\dagger \beta_{\mathbf{k}'} \rangle \right) , \end{aligned}$$

4.2 Beyond HF approximation

Treatment for $\langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle$

scattering term is (based on the reduced four operator term)
difference between this term and the Hartree-Fock approximation

$$\delta \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle = \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle - \langle \alpha_k^\dagger \alpha_k \rangle \langle \alpha_{k-q}^\dagger \alpha_{k-q} \rangle \delta k, k'$$

calculate equation of motion for this term

$$\begin{aligned} \frac{\partial}{\partial t} \delta \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle &= \langle \frac{\partial}{\partial t} (\alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'}) \rangle \\ &- \left[\langle \frac{\partial}{\partial t} (\alpha_k^\dagger \alpha_k) \rangle \langle \alpha_{k-q}^\dagger \alpha_{k-q} \rangle + \langle \alpha_k^\dagger \alpha_k \rangle \langle \frac{\partial}{\partial t} (\alpha_{k-q}^\dagger \alpha_{k-q}) \rangle \right] \delta_{k,k'} \end{aligned}$$

Using the Heisenberg Eq. with the full electron-hole Hamiltonian for time derivatives

4.2 Beyond HF approximation

Coulomb Term → lengthy expression
general expression:

$$\begin{aligned}\frac{\partial}{\partial t} \delta \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle &= \frac{i}{\hbar} \delta \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle \Delta \epsilon_{e,k,k',q} \quad \text{kinetic energy term} \\ &+ \frac{\partial}{\partial t} \delta \langle \alpha_k^\dagger \alpha_{k'-q}^\dagger \alpha_{k-q} \alpha_{k'} \rangle|_{Coulomb} \quad \text{with 6 operator terms}\end{aligned}$$

$$\text{with } \Delta \epsilon_{e,k,k',q} = \epsilon_{e,k} + \epsilon_{e,k'-q} - \epsilon_{e,k-q} - \epsilon_{e,k'}$$

factorized into 2 operator terms

→ leads to carrier Boltzmann scattering rates

4.2 Beyond HF approximation

Carrier Boltzmann scattering rates
for the electron population (e-e and e-h-scatt)

$$\begin{aligned}\frac{\partial n_{e,k}}{\partial t} \Big|_{scatt.} &= - \sum_{k',q \neq 0} \frac{2\pi}{\hbar} V_q^2 \delta(\epsilon_{e,k} + \epsilon_{e,k'} - \epsilon_{e,k+q} - \epsilon_{e,k'-q}) \\ &\times [n_{e,k} n_{e,k'} (1 - n_{e,k+q}) (1 - n_{e,k'-q}) - n_{e,k'-q} n_{e,k+q} (1 - n_{e,k'}) (1 - n_{e,k})] \\ &- \sum_{k',q \neq 0} \frac{2\pi}{\hbar} V_q^2 \delta(\epsilon_{e,k} + \epsilon_{h,k'} - \epsilon_{e,k-q} - \epsilon_{h,k'}) \\ &\times [n_{e,k} n_{h,k'} (1 - n_{e,k+q}) (1 - n_{h,k'-q}) - n_{h,k'-q} n_{e,k+q} (1 - n_{e,k}) (1 - n_{h,k'})] \\ &= -n_{e,k} \Gamma_{e,k}^{\text{out}}(n) + (1 - n_{e,k}) \Gamma_{e,k}^{\text{in}}(n)\end{aligned}$$

$n_{h,k}$: change everywhere $e \leftrightarrow h$

4.2 Beyond HF approximation

Scatt. Term for Polarization in form of

$$\frac{\partial P_k}{\partial t} \Big|_{scatt.} = -A_k P_k + \sum_{q \neq 0} B_{k,q} P_{k+q}$$

with complex functions A and B

- real part of A yields decay rate of polarization

$$\Gamma_k = \Re(A_k) = \frac{1}{2} (\Gamma_{e,k}^{\text{out}}(n) + \Gamma_{e,k}^{\text{in}}(n) + \Gamma_{h,k}^{\text{out}}(n) + \Gamma_{h,k}^{\text{in}}(n))$$

- $\text{Re}(B_{k,q})$ describes rate of polarization transfer between state k and q caused by carrier-carrier collisions.

4.2 Beyond HF approximation

Decay time:

$$\Gamma_k = \Re(A_k) = \frac{1}{2} (\Gamma_{e,k}^{\text{out}}(n) + \Gamma_{e,k}^{\text{in}}(n) + \Gamma_{h,k}^{\text{out}}(n) + \Gamma_{h,k}^{\text{in}}(n)) = \frac{1}{T_2}$$

T_2 is the decay time of the polarization

$$T_2 = 2 \cdot T_1$$

T_1 describes the decay time of carrier population

→ lifetime determined by time an electron/hole spends in its state k rather than recombination time

4.3 LO-phonon scattering

Optical phonons have little dispersion

- described by energy $\hbar\omega_0$
- heterogen semiconductor $\hbar\omega_0$ between 20 to 40meV
- absorption/emission of LO-phonons lead to intraband scattering of carriers
- Intraband scattering Hamiltonian (Fröhlich H.):

$$H_{e-LO} = \sum_{i,k,q} \hbar g_q \alpha_{i,k+q}^\dagger \alpha_{i,k} (b_q + b_{-q}^\dagger)$$

With the bosonic phonon annihilation and creation operators b_q and b_{-q}^\dagger

4.3 LO-phonon scattering

Fröhlich Hamiltonian

$$H_{e-LO} = \sum_{i,k,q} \hbar g_q \alpha_{i,k+q}^\dagger \alpha_{i,k} (b_q + b_{-q}^\dagger)$$

Interaction matrix:

$$|g_q|^2 = \frac{\omega_0 V_q}{2\hbar} \left(\frac{1}{\epsilon_\infty} - \frac{1}{\epsilon_0} \right)$$

V_q : Coulomb matrix element

ϵ_∞ : high frequency dielectric constant

ϵ_0 : low frequency dielectric constant

V_q shows coulombic nature in exchange of optical phonons in carrier-carrier interaction

4.3 LO-phonon scattering

Collision term of LO-phonon scattering:

$$\begin{aligned}\frac{\partial \rho_{i,j}(k)}{\partial t} \Big|_{scatt} &= \frac{i}{\hbar} \langle ([H_{e-LO}, \alpha_{j,k}^\dagger] \alpha_{i,k} + \alpha_{j,k}^\dagger [H_{e-LO}, \alpha_{i,k}]) \rangle \\ &= i \sum_q g_q \left(\langle \alpha_{j,k+q}^\dagger \alpha_{i,k} (b_q + b_{-q}^\dagger) \rangle - \langle \alpha_{j,k}^\dagger \alpha_{i,k-q} (b_q + b_{-q}^\dagger) \rangle \right) \\ &= i \sum_q g_q \left(F_{ij,k,q}^- + F_{ij,k,q}^+ - G_{ij,k,q}^- - G_{ij,k,q}^+ \right)\end{aligned}$$

term couples expectation values of two electron and one phonon operator.

phonon assisted density matrices

$$\begin{array}{ll} F_{ij,k,q}^- = \langle \alpha_{j,k+q}^\dagger \alpha_{i,k} b_q \rangle & F_{ij,k,q}^+ = \langle \alpha_{j,k+q}^\dagger \alpha_{i,k} b_{-q}^\dagger \rangle \\ G_{ij,k,q}^- = \langle \alpha_{j,k}^\dagger \alpha_{i,k-q} b_q \rangle & G_{ij,k,q}^+ = \langle \alpha_{j,k}^\dagger \alpha_{i,k-q} b_{-q}^\dagger \rangle \end{array}$$

4.3 LO-phonon scattering

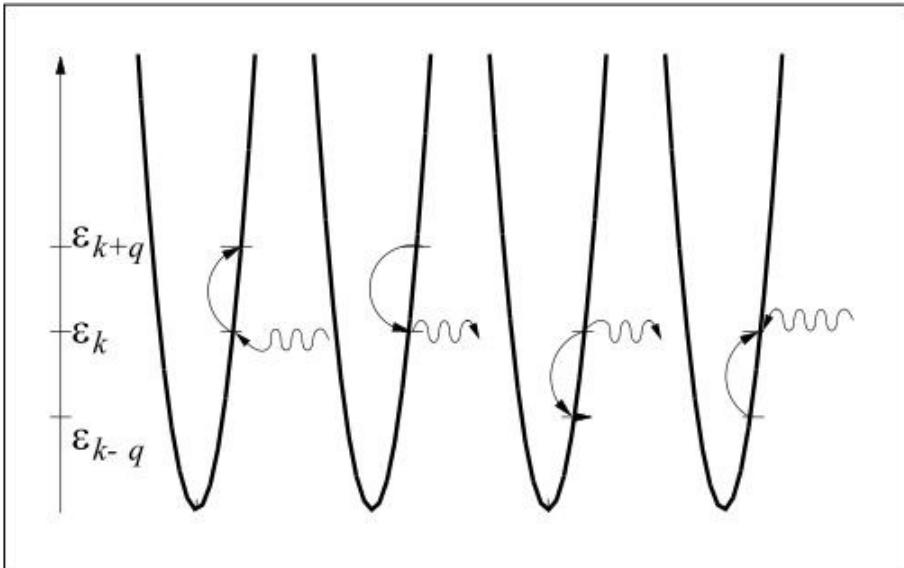


Fig. 1: Sketch of electron phonon scattering processes
(solid lines: electron scattering between states. Curled lines: phonon absorption / emission)

Equation of motion for phonon assisted density matrices is:

$$\frac{\partial F_{ij,k,q}}{\partial t} = \frac{i}{\hbar} \langle [H_{e-LO} + H_{HF} + H_{LO}, a_{j,k+q}^\dagger a_{i,k} b_q] \rangle$$

Conclusion

Semiconductor Bloch Equations:

- Set of coupled equations to describe polarization and population dynamics
- Levels of approximation
 - Low excitation: independant excitons
 - Scattering:
 - Decay rates
 - 4-operator density matrices
 - Phonon assisted processes

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